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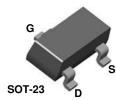
# J175 / J176 / MMBFJ175 / MMBFJ176 / MMBFJ177 P-Channel Switch

# Description

This device is designed for low-level analog switching sample-and-hold circuits and chopper-stabilized amplifiers. Sourced from process 88.



Figure 1. J175 / J176 Device Package



Mark: 6W / 6X / 6Y Note: Source & drain are interchangeable.

Figure 2. MMBFJ175 / 176 / 177 Device Package

## **Ordering Information**

Part Number	Marking	Package	Packing Method
J175-D26Z	J175	TO-92 3L	Tape and Reel
J176-D74Z	J176	TO-92 3L	Ammo
MMBFJ175	6W	SOT-23 3L	Tape and Reel
MMBFJ176	6X	SOT-23 3L	Tape and Reel
MMBFJ177	6Y	SOT-23 3L	Tape and Reel

# Absolute Maximum Ratings<sup>(1),(2)</sup>

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>DG</sub>	Drain-Gate Voltage	-30	V
V <sub>GS</sub>	Gate-Source Voltage	30	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to + 150	°C

### Notes:

- 1. These ratings are based on a maximum junction temperature of 150°C.
- 2. These are steady-state limits. ON Semiconductor should be consulted on applications involving pulsed or lowduty cycle operations.

# **Thermal Characteristics**

Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

		Ma			
Symbol	Parameter	J175 / J176 <sup>(3)</sup>	MMBFJ175 / MMBFJ176 / MMBFJ177 <sup>(3)</sup>	Onit	
PD	Total Device Dissipation	350	225	mW	
	Derate Above 25°C	2.8	1.8	mW/°C	
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	125		°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W	

### Note:

3. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

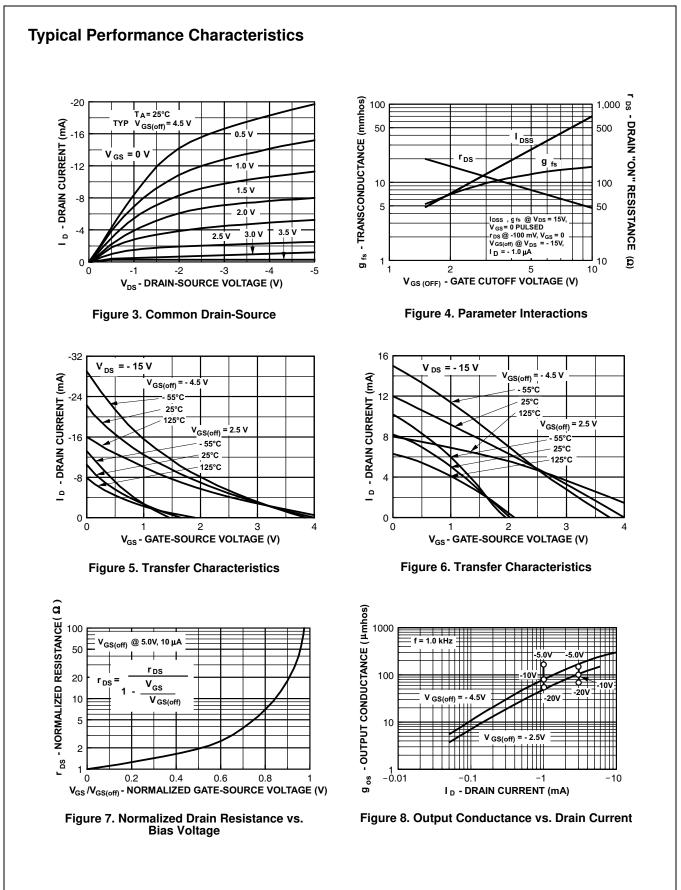
# **Electrical Characteristics**

Values are at  $T_A$  = 25°C unless otherwise noted.

Symbol	Parameter	Conditions		Min.	Max.	Unit
Off Charact	eristics				•	•
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_{G}$ = 1.0 $\mu$ A, $V_{DS}$ = 0		30		V
I <sub>GSS</sub>	Gate Reverse Current	V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0			1.0	nA
V <sub>GS(off)</sub>	Gate-Source Cut-Off Voltage	V <sub>DS</sub> = -15 V, I <sub>D</sub> = -10 nA	J175 / MMBFJ175	3.0	6.0	v
			J176 / MMBFJ176	1.0	4.0	
			MMBFJ177	0.8	2.5	
On Charact	eristics					
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current <sup>(4)</sup>	V <sub>DS</sub> = -15 V, I <sub>GS</sub> = 0	J175 / MMBFJ175	-7.0	-60.0	mA
			J176 / MMBFJ176	-2.0	-25.0	
			MMBFJ177	-1.5	-20.0	
۲ <sub>DS(on)</sub>	Drain-Source On Resistance	$V_{DS} \le 0.1 \text{ V}, V_{GS} = 0$	J175 / MMBFJ175		125	Ω
			J176 / MMBFJ176		250	
			MMBFJ177		300	

### Note:

4. Pulse test: pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2.0\%.$ 



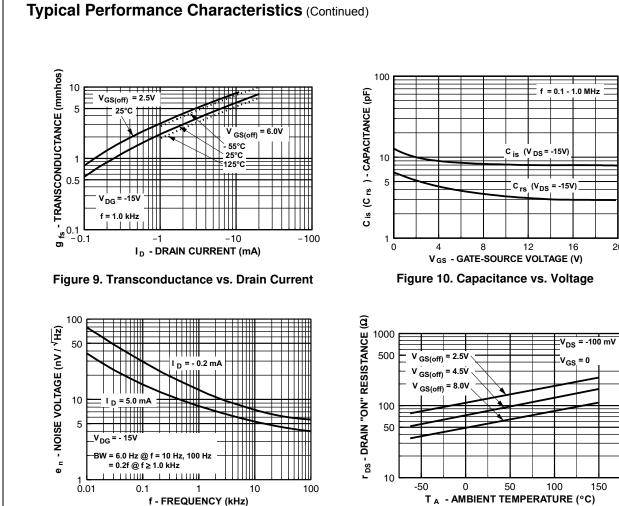


Figure 11. Noise Voltage vs. Frequency

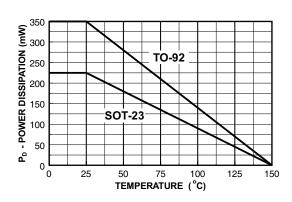
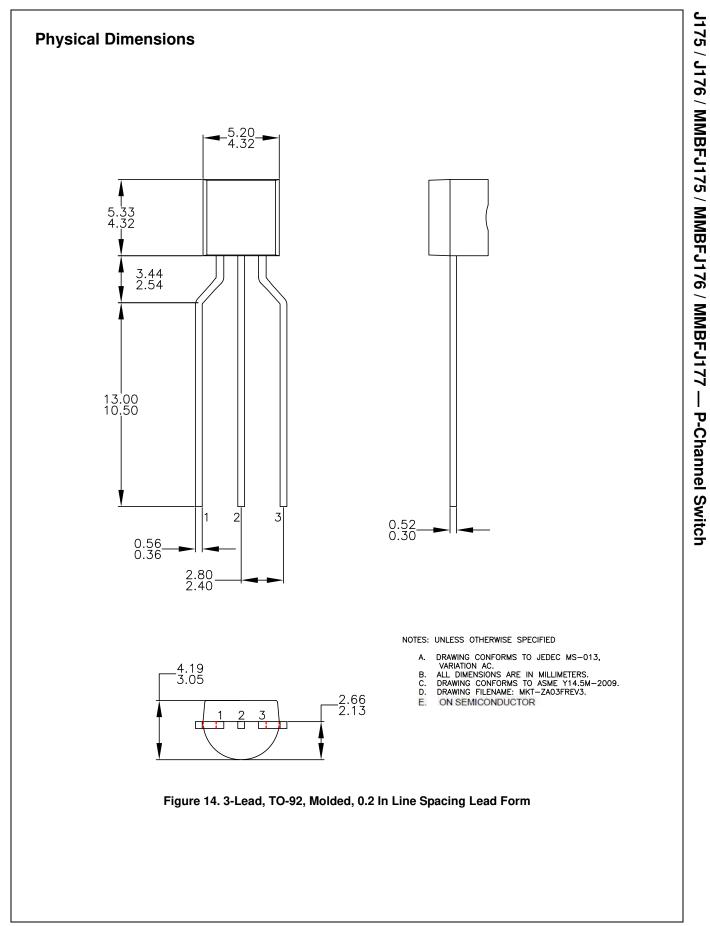
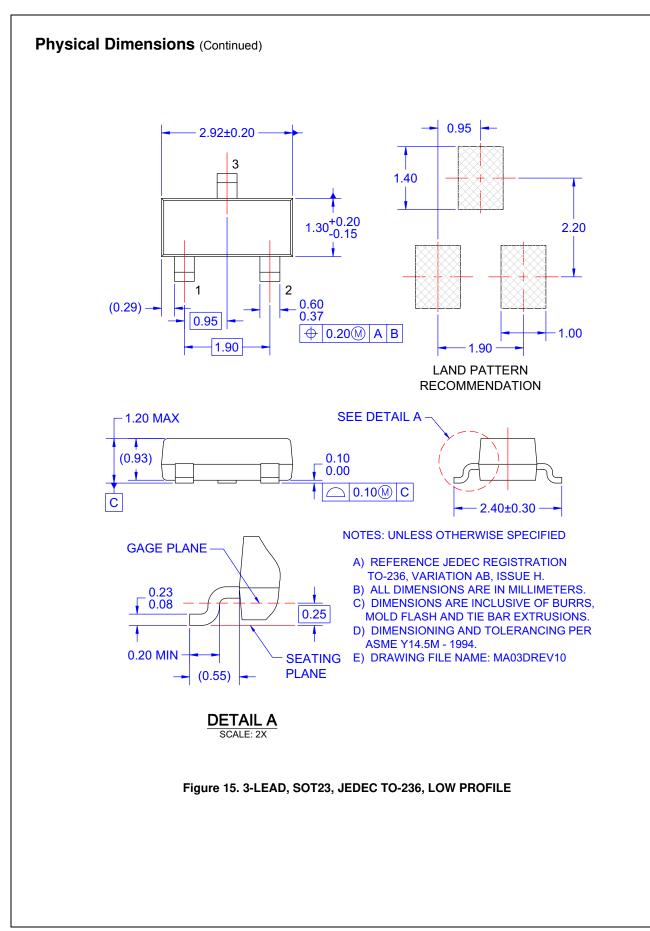




Figure 12. Channel Resistance vs. Temperature

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